.M710 Voltage Comparator



LM710 Voltage Comparator

General Description

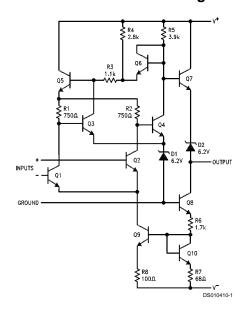
The LM710 series are high-speed voltage comparators intended for use as an accurate, low-level digital level sensor or as a replacement for operational amplifiers in comparator applications where speed is of prime importance. The circuit has a differential input and a single-ended output, with saturated output levels compatible with practically all types of integrated logic.

The device is built on a single silicon chip which insures low offset and thermal drift. The use of a minimum number of stages along with minority-carrier lifetime control (gold doping) makes the circuit much faster than operational amplifi-

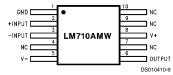
ers in saturating comparator applications. In fact, the low stray and wiring capacitances that can be realized with monolithic construction make the device difficult to duplicate with discrete components operating at equivalent power levels

The LM710 series are useful as pulse height discriminators, voltage comparators in high-speed A/D converters or go, no-go detectors in automatic test equipment. They also have applications in digital systems as an adjustable-threshold line receiver or an interface between logic types. In addition, the low cost of the units suggests them for applications replacing relatively simple discrete component circuitry.

Schematic and Connection Diagrams



Ceramic Flatpak Package



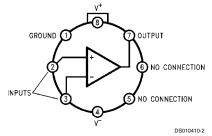
* Also available per JM38510/10301

Order Number LM710AMW/883* See NS Package Number W10A

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Schematic and Connection Diagrams (Continued)

Metal Can Package

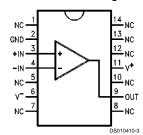


Pin 4 is connected to case.

Top View Order Number LM710AMH/883*, LM710H, LM710H/883 or LM710CH See NS Package Number H08C

* Also available per JM38510/10301

Dual-In-Line Package



Top View Order Number LM710AMJ/883* or LM710CN See NS Package Number N14A or J14A

Absolute Maximum Ratings (Note *NO TARGET FOR FNXref NS0053*)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Positive Supply Voltage +14V Negative Supply Voltage -7V 10 mA Peak Output Current Output Short Circuit Duration 10 seconds

Differential Input Voltage ±5V Input Voltage ±7V Power Dissipation

TO-99 (Note 1) 700 mW

Plastic Dual-In-Line Package

(Note 2) 950 mW

Operating Temperature Range

LM710 -55°C to +125°C LM710C 0°C to +70°C Storage Temperature Range -65°C to +150°C

Lead Temperature

260°C (Soldering, 10 sec.)

Electrical Characteristics (Note 3)

Parameter	Conditions	LM710			LM710C			Units
		Min	Тур	Max	Min	Тур	Max	
Input Offset Voltage	$R_S \le 200\Omega, V_{CM} = 0V, T_A = 25^{\circ}C$		0.6	2.0		1.6	5.0	mV
Input Offset Current	V _{OUT} = 1.4V, T _A = 25°C		0.75	3.0		1.8	5.0	μΑ
Input Bias Current	T _A = 25°C		13	20		16	25	μΑ
Voltage Gain	T _A = 25°C	1250	1700		1000	1500		
Output Resistance	T _A = 25°C		200			200		Ω
Output Sink Current	V _{OUT} = 0, T _A = 25°C							
	$\Delta V_{IN} \ge 5 \text{ mV}$	2.0	2.5					mA
	$\Delta V_{IN} \ge 10 \text{ mV}$				1.6	2.5		mA
Response Time	T _A = 25°C (Note 4)		40			40		ns
Input Offset Voltage	$R_S \le 200\Omega$, $V_{CM} = 0V$			3.0			6.5	mV
Average Temperature Coefficient	$T_{MIN} \le T_A \le T_{MAX}$		3.0	10		5.0	20	μV/°C
of Input Offset Voltage	$R_{\rm S} \leq 50\Omega$							-
Input Offset Current	$T_A = T_{A \text{ MAX}}$		0.25	3.0			7.5	μΑ
	$T_A = T_{A MIN}$		1.8	7.0			7.5	μA
Average Temperature Coefficient	$25^{\circ}\text{C} \leq \text{T}_{\text{A}} \leq \text{T}_{\text{MAX}}$		5.0	25		15	50	nA/°C
of Input Offset Current	$T_{MIN} \le T_A \le 25^{\circ}C$		15	75		24	100	nA/°C
Input Bias Current	T _A = T _{MIN}		27	45		25	40	μA
Input Voltage Range	V ⁻ = -7V	±5.0			±5.0			V
Common-Mode Rejection Ratio	$R_S \le 200\Omega$	80	100		70	98		dB
Differential Input Voltage Range		±5.0			±5.0			V
Voltage Gain		1000			800			V/V
Positive Output Level	-5 mA ≤ I _{OUT} ≤ 0							
	V _{IN} ≥ 5 mV	2.5	3.2	4.0				V
	V _{IN} ≥ 10 mV				2.5	3.2	4.0	V
Negative Output Level	V _{IN} ≥ 5 mV	-1.0	-0.5	0				V
	V _{IN} ≥ 10 mV				-1.0	-0.5	0	V
Output Sink Current	$V_{IN} \ge 5 \text{ mV}, V_{OUT} = 0$							
	T _A = 125°C	0.5	1.7					mA
	$T_A = -55^{\circ}C$	1.0	2.3					mA
	$V_{IN} \ge 10 \text{ mV}, V_{OUT} = 0$				0.5			mA
	0°C ≤ T _A ≤ +70°C							
Positive Supply Current	V _{IN} ≥ 5 mV		5.2	9.0				mA
	V _{IN} ≥ 10 mV					5.2	9.0	mA
Negative Supply Current	$V_{IN} \ge 5 \text{ mV}$		4.6	7.0				mA
	V _{IN} ≥ 10 mV					4.6	7.0	mA

Electrical Characteristics (Note 3) (Continued)

Parameter	Conditions	LM710			LM710C			Units
		Min	Тур	Max	Min	Тур	Max	
Power Consumption	I _{OUT} = 0							
	V _{IN} ≥ 5 mV		90	150				mW
	V _{IN} ≥ 10 mV						150	mW

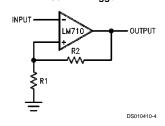
- Note 1: Rating applies for ambient temperatures of 25°C; derate linearly at 5.6 mW/°C for ambient temperatures above 25°C.
- Note 2: Derate linearly at 9.5 mW/°C for ambient temperatures above 25°C.

Note 3: These specifications appy for V^+ = 12V, V^- = -6V, -55°C \leq T_A \leq +125°C for LM710 and 0°C \leq T_A \leq +70°C for LM710C unless otherwise specified: The input offset voltage and input offset current (see definitions) are specified for a logic threshold voltage of 1.8V at -55°C, 1.4V at 25°C, and 1V at 125°C for LM710 and 1.5V at 0°C, 1.4V at 25°C, and 1.2V at 70°C for LM710C.

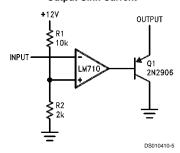
Note 4: The response time specified (see definitions) is for a 100 mV input step with 5 mV overdrive (LM710) or a 10 mV overdrive (LM710C).

Typical Applications

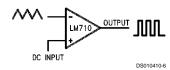
Schmitt Trigger



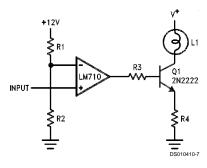
Line Receive with Increased Output Sink Current



Pulse Width Modulator

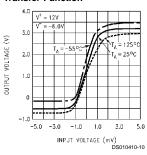


Level Detector with Lamp Driver

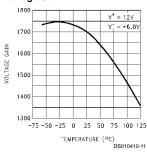


Typical Performance Characteristics

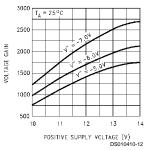
Transfer Function



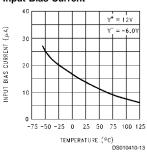
Voltage Gain



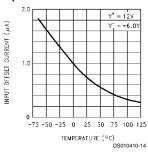
Voltage Gain



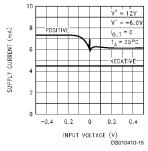
Input Bias Current



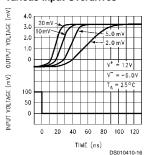
Input Offset Current



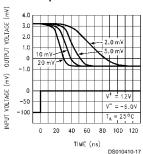
Supply Current



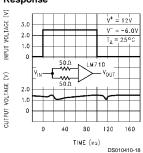
Response Time for Various Input Overdrives



Response Time for Various Input Overdrives

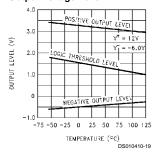


Common Mode Pulse Response

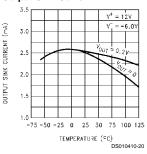


Typical Performance Characteristics (Continued)

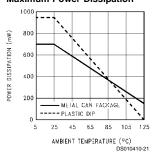
Output Voltage Level



Output Sink Current



Maximum Power Dissipation

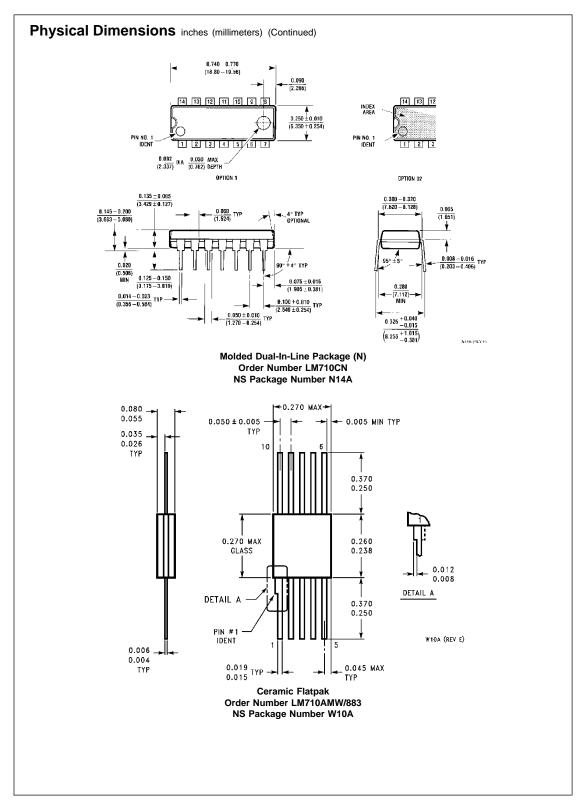


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